



TECHNICAL REPORT



Optical amplifiers – Part 9: Semiconductor optical amplifiers (SOAs)

INTERNATIONAL
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CONTENTS

FOREWORD.....	4
INTRODUCTION.....	6
1 Scope.....	7
2 Normative references	7
3 Terms, definitions, abbreviated terms and symbols.....	7
3.1 Terms and definitions.....	7
3.2 Abbreviated terms.....	8
3.3 Symbols.....	9
4 Specific features of SOAs.....	9
4.1 SOA chips.....	9
4.2 Gain ripple	12
4.2.1 General	12
4.2.2 Theoretical calculation of gain ripple.....	14
4.3 Polarization dependent gain (PDG).....	17
4.3.1 General	17
4.3.2 Polarization insensitive SOAs	17
4.4 Noise figure (NF)	18
4.5 Lifetime of carriers	18
4.6 Nonlinear effects.....	18
5 Measurement of SOA output power and PDG	18
5.1 Narrow-band versus broadband light source	18
5.2 Examples of measurement results	19
Annex A (informative) Applications of SOAs.....	23
A.1 General.....	23
A.2 Polarization mode of SOAs	23
A.3 Reach extender for GPON	23
A.4 Pre-amplifier in transceivers for 100 Gbit Ethernet.....	23
A.5 Monolithic integration of SOAs.....	24
A.6 Reflective SOAs (RSOAs).....	25
Bibliography.....	26
Figure 1 – Schematic diagram of the typical SOA chip	10
Figure 2 – Example of gain dependency of an SOA chip on forward current.....	10
Figure 3 – Schematic top view of a typical SOA chip with and without an angled waveguide structure.....	11
Figure 4 – Schematic top view of a typical SOA module.....	12
Figure 5 – Schematic diagram of the optical feedback inside the SOA chip.....	13
Figure 6 – Schematic diagram of gain ripple	13
Figure 7 – Illustrated model of a Fabry-Perot type SOA	14
Figure 8 – Illustrated model of ASE output from an SOA.....	15
Figure 9 – SOA output power and PDG dependence on wavelength	19
Figure 10 – Optical power spectra of three different SOA chips.....	20
Figure 11 – Output power and PDG of SOA chip sample 1 as a function of I_F	21
Figure 12 – Output power and PDG of SOA chip sample 2 as a function of I_F	21

Figure 13 – Output power and PDG of SOA chip sample 3 as a function of I_F	22
Figure A.1 – Schematic diagram of the receiver section of SOA-incorporated CFP transceivers	24
Figure A.2 – Schematic diagram of the DFB-LDs-array type wavelength tuneable LD	25
Figure A.3 – Schematic diagram of a seeded WDM-PON system	25

INTERNATIONAL ELECTROTECHNICAL COMMISSION

OPTICAL AMPLIFIERS –

Part 9: Semiconductor optical amplifiers (SOAs)

FOREWORD

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IEC TR 61292-9 has been prepared by subcommittee 86C: Fibre optic systems and active devices, of IEC technical committee 86: Fibre optics. It is a Technical Report.

This third edition cancels and replaces the second edition published in 2017. This edition constitutes a technical revision.

This edition includes the following significant technical changes with respect to the previous edition:

- a) revised definitions for SOAs in 3.1;
- b) added more theoretical background on gain ripple measurements using amplified spontaneous emission (ASE) spectrum in 4.3;
- c) removed the formerly preferred set-up for output power and PDG measurements in Clause 5.

This is a preview of "IEC/TR 61292-9 Ed. 3...". Click here to purchase the full version from the ANSI store.

The text of this Technical Report is based on the following documents:

Draft	Report on voting
86C/1820/DTR	86C/1830/RVDTR

Full information on the voting for its approval can be found in the report on voting indicated in the above table.

The language used for the development of this Technical Report is English.

This document was drafted in accordance with ISO/IEC Directives, Part 2, and developed in accordance with ISO/IEC Directives, Part 1 and ISO/IEC Directives, IEC Supplement, available at www.iec.ch/members_experts/refdocs. The main document types developed by IEC are described in greater detail at www.iec.ch/publications.

A list of all parts in the IEC 61292 series, published under the general title *Optical amplifiers*, can be found on the IEC website.

The committee has decided that the contents of this document will remain unchanged until the stability date indicated on the IEC website under webstore.iec.ch in the data related to the specific document. At this date, the document will be

- reconfirmed,
- withdrawn,
- replaced by a revised edition, or
- amended.

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INTRODUCTION

Optical amplifiers (OAs) are essential components for fibre optic communication systems, where they serve as booster amplifiers, in-line amplifiers, and pre-amplifiers. Numerous standards have been published for OAs (e.g., the IEC 61290 series and IEC 61291 series). However, most of these standards focus on optical fibre amplifiers (OFAs) because these are commonly deployed in commercial fibre optic networks. Recently, semiconductor optical amplifiers (SOAs) have attracted attention for applications in Gbit passive optical networks (GPONs) and Gbit Ethernet (GbE) systems, which operate at line rates of 100 Gbit/s and beyond. SOA chips are as small as laser diodes (LDs) and are directly driven by an electrical current.

Although SOAs operating in the 1 310 nm or 1 550 nm wavelength bands have been extensively studied since the 1980s, SOAs have mostly been used in laboratories or in field trials. This is due to certain performance limitations of SOAs, such as gain ripple and polarization dependent gain (PDG). As a result, there are few IEC documents addressing SOAs. One exception is IEC TR 61292-3, which is a Technical Report on classification, characteristics, and applications of OAs including SOAs. However, IEC TR 61292-3 presents only general information on SOAs and does not contain detailed information on test methods for measuring the particular performance parameters of SOAs.

IEC 61290-1-1:2020 describes test methods for power and gain parameters of OAs, which includes a method for gain ripple measurements on SOAs. This document has been revised to harmonize its content with IEC 61290-1-1 and with IEC 61291-2.

This document provides more detailed descriptions of the specific features of SOAs, including information on gain ripple and PDG.

OPTICAL AMPLIFIERS –

Part 9: Semiconductor optical amplifiers (SOAs)

1 Scope

This part of IEC 61292, which is a Technical Report, describes the characteristic features of semiconductor optical amplifiers (SOAs), including the specific features of gain ripple and polarization dependent gain (PDG).

This document focuses on amplifying applications of SOAs. Other applications, such as modulation, switching and non-linear functions, are not covered.

Potential applications of SOAs, such as reflective SOAs (RSOAs) for the seeded wavelength division multiplexing passive optical network (WDM-PON), are reviewed in Annex A.

2 Normative references

The following documents are referred to in the text in such a way that some or all of their content constitutes requirements of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC 61291-1:2018, *Optical amplifiers – Part 1: Generic specification*

IEC 61291-2:2016, *Optical amplifiers – Part 2: Single channel applications – Performance specification template*

3 Terms, definitions, abbreviated terms and symbols

3.1 Terms and definitions

For the purposes of this document, the terms and definitions given in IEC 61291-1:2018, IEC 61291-2:2016, and the following apply.

ISO and IEC maintain terminological databases for use in standardization at the following addresses:

- IEC Electropedia: available at <http://www.electropedia.org/>
- ISO Online browsing platform: available at <http://www.iso.org/obp>

3.1.1

SOA

semiconductor optical amplifier

optical amplifier in which the active optical waveguide is formed by a semiconductor laser diode structure, which is electrically pumped

Note 1 to entry: SOAs have a similar structure to Fabry-Perot semiconductor laser diodes but with anti-reflection elements at the end surfaces. The optical signal is amplified through the stimulated emission phenomenon in the gain medium.

[SOURCE: IEC 61291-2:2016, 3.1.3, modified – Note 1 to entry has been added.]